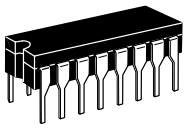
MC14504B

Hex Level Shifter for TTL to CMOS or CMOS to CMOS

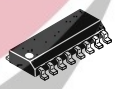
The MC14504B is a hex non–inverting level shifter using CMOS technology. The level shifter will shift a TTL signal to CMOS logic levels for any CMOS supply voltage between 5 and 15 volts. A control input also allows interface from CMOS to CMOS at one logic level to another logic level: Either up or down level translating is accomplished by selection of power supply levels V_{DD} and V_{CC}. The V_{CC} level sets the input signal levels while V_{DD} selects the output voltage levels.

- UP Translates from a Low to a High Voltage or DOWN Translates from a High to a Low Voltage
- Input Threshold Can Be Shifted for TTL Compatibility
- No Sequencing Required on Power Supplies or Inputs for Power Up or Power Down
- 3 to 18 Vdc Operation for V_{DD} and V_{CC}
- Diode Protected Inputs to V_{SS}
- Capable of Driving Two Low–Power TTL Loads or One Low–Power Schottky TTL Load Over the Rated Temperature Range



L SUFFIX
CERAMIC
CASE 620

P SUFFIX
PLASTIC
CASE 648



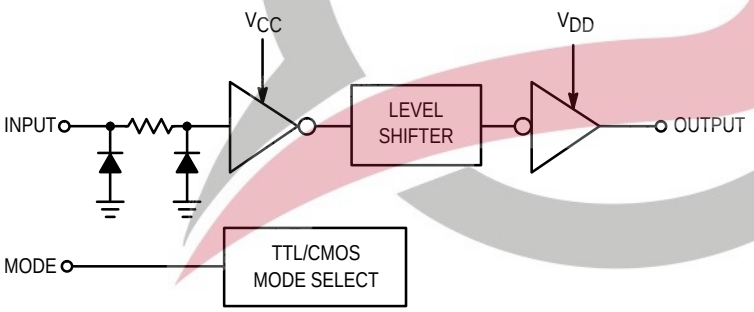
D SUFFIX
SOIC
CASE 751B

ORDERING INFORMATION

MC14XXXBCP	Plastic
MC14XXXBCL	Ceramic
MC14XXXBD	SOIC

T_A = – 55° to 125°C for all packages.

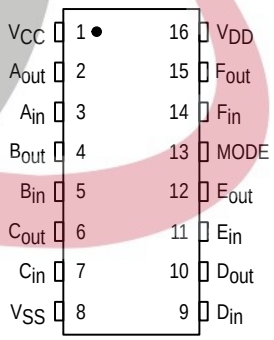
LOGIC DIAGRAM



Mode Select	Input Logic Levels	Output Logic Levels
1 (V_{CC})	TTL	CMOS
0 (V_{SS})	CMOS	CMOS

1/6 of package shown.

PIN ASSIGNMENT



This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields referenced to the V_{SS} pin, only. Extra precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, the ranges $V_{SS} \le V_{in} \le 18$ V and $V_{SS} \le V_{out} \le V_{DD}$ are recommended.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.

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MAXIMUM RATINGS* (Voltages Referenced to V_{SS})

Symbol	Parameter	Value	Unit
V_{CC}	DC Supply Voltage	– 0.5 to 18.0	V
V_{DD}	DC Supply Voltage	– 0.5 to + 18.0	V
V_{in}	Input Voltage (DC or Transient)	– 0.5 to + 18.0	V
V_{out}	Output Voltage (DC or Transient)	– 0.5 to V_{DD} + 0.5	V
I_{in}, I_{out}	Input or output Current (DC or Transient), per Pin	± 10	mA
P_D	Power Dissipation, per Package*	500	mW
T_{stg}	Storage Temperature	– 65 to + 150	°C
T_L	Lead Temperature (8–Second Soldering)	260	°C

* Maximum Ratings are those values beyond which damage to the device may occur.
†Temperature Derating:
Plastic "P and D/DW" Packages: – 7.0 mW/°C From 65°C To 125°C
Ceramic "L" Packages: – 12 mW/°C From 100°C To 125°C

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

Characteristic	Symbol	V_{CC} Vdc	V_{DD} Vdc	– 55°C Min	– 55°C Max	25°C Min	25°C Typ #	25°C Max	125°C Min	125°C Max	Unit
Output Voltage "0" Level	V_{OL}	—	5.0	—	0.05	—	0	0.05	—	0.05	Vdc
V_{in} = 0 V		—	10	—	0.05	—	0	0.05	—	0.05	
		—	15	—	0.05	—	0	0.05	—	0.05	
"1" Level	V_{OH}	—	5.0	4.95	—	4.95	5.0	—	4.95	—	Vdc
V_{in} = V_{CC}		—	10	9.95	—	9.95	10	—	9.95	—	
		—	15	14.95	—	14.95	15	—	14.95	—	
Input Voltage "0" Level	V_{IL}										Vdc
(V_{OL} = 1.0 Vdc) TTL–CMOS		5.0	10	—	0.8	—	1.3	0.8	—	0.8	
(V_{OL} = 1.5 Vdc) TTL–CMOS		5.0	15	—	0.8	—	1.3	0.8	—	0.8	
(V_{OL} = 1.0 Vdc) CMOS–CMOS		5.0	10	—	1.5	—	2.25	1.5	—	1.4	
(V_{OL} = 1.5 Vdc) CMOS–CMOS		5.0	15	—	1.5	—	2.25	1.5	—	1.5	
(V_{OL} = 1.5 Vdc) CMOS–CMOS		10	15	—	3.0	—	4.5	3.0	—	2.9	
Input Voltage "1" Level	V_{IH}										Vdc
(V_{OH} = 9.0 Vdc) TTL–CMOS		5.0	10	2.0	—	2.0	1.5	—	2.0	—	
(V_{OH} = 13.5 Vdc) TTL–CMOS		5.0	15	2.0	—	2.0	1.5	—	2.0	—	
(V_{OH} = 9.0 Vdc) CMOS–CMOS		5.0	10	3.6	—	3.5	2.75	—	3.5	—	
(V_{OH} = 13.5 Vdc) CMOS–CMOS		5.0	15	3.6	—	3.5	2.75	—	3.5	—	
(V_{OH} = 13.5 Vdc) CMOS–CMOS		10	15	7.1	—	7.0	5.5	—	7.0	—	
Output Drive Current	I_{OH}										mAdc
(V_{OH} = 2.5 Vdc) Source		—	5.0	– 3.0	—	– 2.4	– 4.2	—	– 1.7	—	
(V_{OH} = 4.6 Vdc)		—	5.0	–0.64	—	–0.51	– 0.88	—	–0.36	—	
(V_{OH} = 9.5 Vdc)		—	10	– 1.6	—	– 1.3	– 2.25	—	– 0.9	—	
(V_{OH} = 13.5 Vdc)		—	15	– 4.2	—	– 3.4	– 8.8	—	– 2.4	—	
(V_{OL} = 0.4 Vdc) Sink	I_{OL}	—	5.0	0.64	—	0.51	0.88	—	0.36	—	mAdc
(V_{OL} = 0.5 Vdc)		—	10	1.6	—	1.3	2.25	—	0.9	—	
(V_{OL} = 1.5 Vdc)		—	15	4.2	—	3.4	8.8	—	2.4	—	
Input Current	I_{in}	—	15	—	± 0.1	—	±0.00001	± 0.1	—	± 1.0	µAdc
Input Capacitance (V_{in} = 0)	C_{in}	—	—	—	—	—	5.0	7.5	—	—	pF
Quiescent Current	I_{DD} or	—	5.0	—	0.05	—	0.0005	0.05	—	1.5	µAdc
(Per Package)	I_{CC}	—	10	—	0.10	—	0.0010	0.10	—	3.0	
CMOS–CMOS Mode		—	15	—	0.20	—	0.0015	0.20	—	6.0	
Quiescent Current	I_{DD}	5.0	5.0	—	0.5	—	0.0005	0.5	—	3.8	µAdc
(Per Package)		5.0	10	—	1.0	—	0.0010	1.0	—	7.5	
TTL–CMOS Mode		5.0	15	—	2.0	—	0.0015	2.0	—	15	
Quiescent Current	I_{CC}	5.0	5.0	—	5.0	—	2.5	5.0	—	6.0	mAdc
(Per Package)		5.0	10	—	5.0	—	2.5	5.0	—	6.0	
TTL–CMOS Mode		5.0	15	—	5.0	—	2.5	5.0	—	6.0	

#Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

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SWITCHING CHARACTERISTICS (C_L = 50 pF, T_A = 25°C)

Characteristic	Symbol	Shifting Mode	V_{CC} Vdc	V_{DD} Vdc	Limits Min	Limits Typ #	Limits Max	Unit
Propagation Delay, High to Low	t_{PHL}	TTL – CMOS $V_{DD} > V_{CC}$	5.0 5.0	10 15	— —	140 140	280 280	ns
		CMOS – CMOS $V_{DD} > V_{CC}$	5.0 5.0 10	10 15 15	— — —	120 120 70	240 240 140	
		CMOS – CMOS $V_{CC} > V_{DD}$	10 15 15	5.0 5.0 10	— — —	185 185 175	370 370 350	
Propagation Delay, Low to High	t_{PLH}	TTL – CMOS $V_{DD} > V_{CC}$	5.0 5.0	10 15	— —	170 160	340 320	ns
		CMOS – CMOS $V_{DD} > V_{CC}$	5.0 5.0 10	10 15 15	— — —	170 170 100	340 340 200	
		CMOS – CMOS $V_{CC} > V_{DD}$	10 15 15	5.0 5.0 10	— — —	275 275 145	550 550 290	
Output Rise and Fall Time	t_{TLH}, t_{THL}	ALL	— — —	5.0 10 15	— — —	100 50 40	200 100 80	ns

#Data labelled “Typ” is not to be used for design purposes but is intended as an indication of the IC’s potential performance.

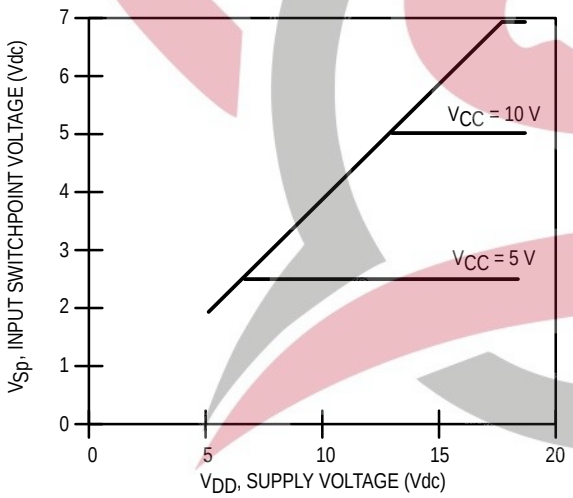

Figure 1. Input Switchpoint CMOS to CMOS Mode

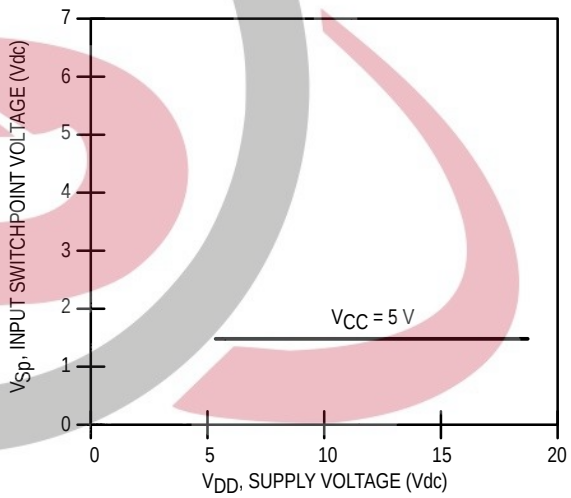

Figure 2. Input Switchpoint TTL to CMOS Mode

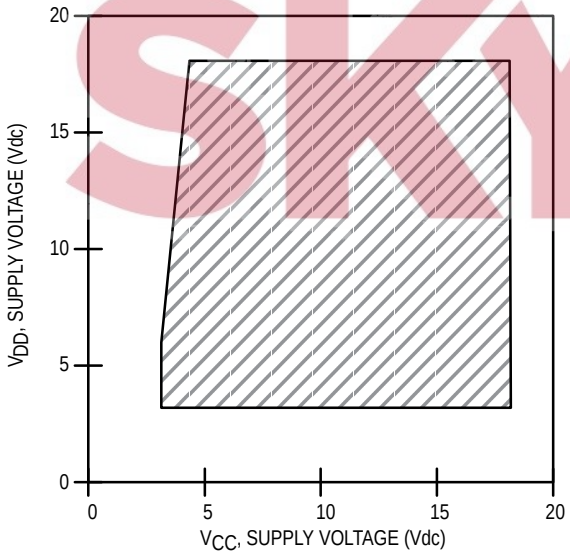

Figure 3. Operating Boundary CMOS to CMOS Mode

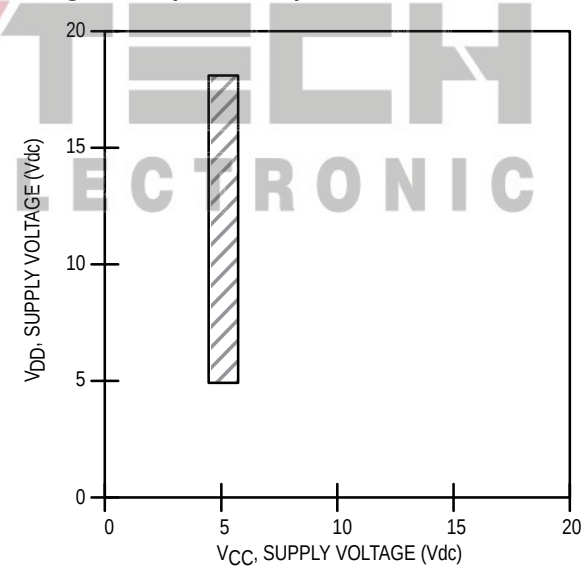

Figure 4. Operating Boundary TTL to CMOS Mode

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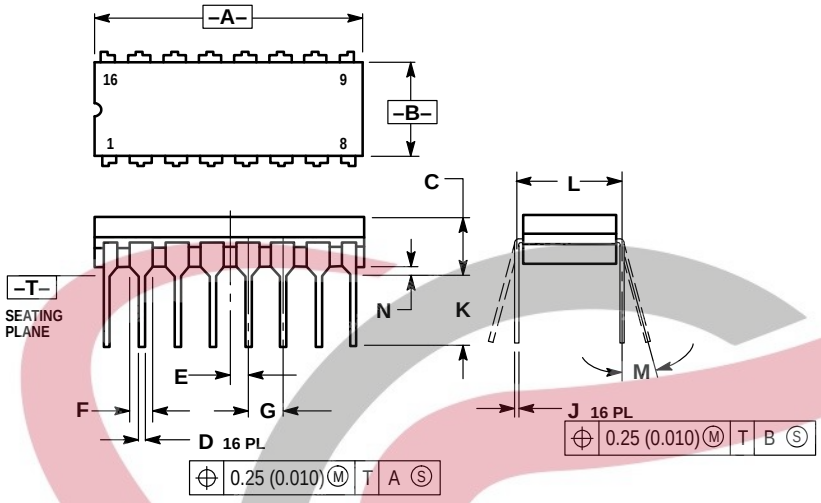
OUTLINE DIMENSIONS

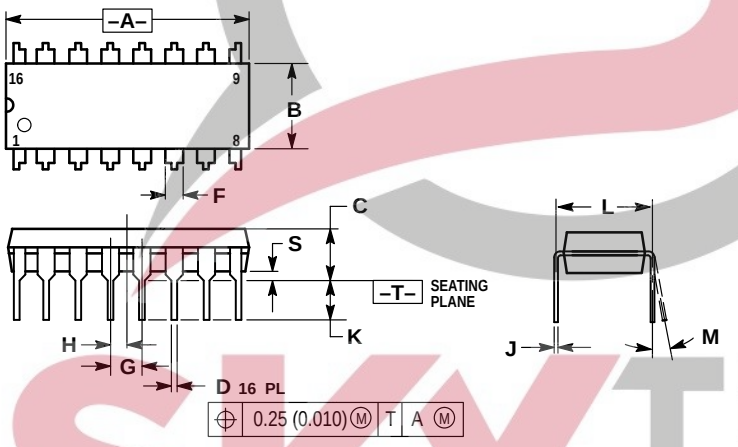
L SUFFIX
CERAMIC DIP PACKAGE
CASE 620–10
ISSUE V



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
4. DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.750	0.785	19.05	19.93
B	0.240	0.295	6.10	7.49
C	—	0.200	—	5.08
D	0.015	0.020	0.39	0.50
E	0.050 BSC		1.27 BSC	
F	0.055	0.065	1.40	1.65
G	0.100 BSC		2.54 BSC	
H	0.008	0.015	0.21	0.38
K	0.125	0.170	3.18	4.31
L	0.300 BSC		7.62 BSC	
M	0 °	15 °	0 °	15 °
N	0.020	0.040	0.51	1.01

P SUFFIX
PLASTIC DIP PACKAGE
CASE 648–08
ISSUE R



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.740	0.770	18.80	19.55
B	0.250	0.270	6.35	6.85
C	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100 BSC		2.54 BSC	
H	0.050 BSC		1.27 BSC	
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
M	0 °	10 °	0 °	10 °
S	0.020	0.040	0.51	1.01

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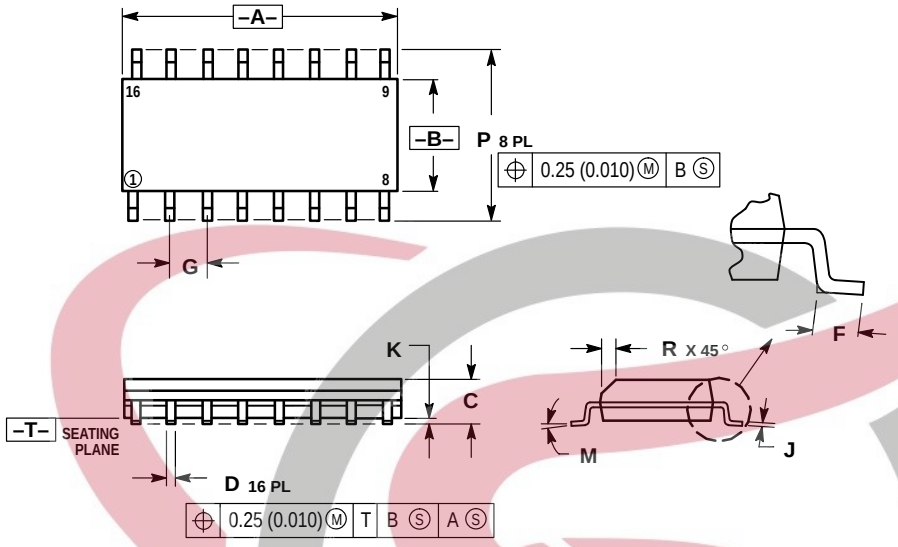
OUTLINE DIMENSIONS

D SUFFIX
PLASTIC SOIC PACKAGE
CASE 751B–05
ISSUE J



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	9.80	10.00	0.386	0.393
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

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